NSN 5962-01-067-8314

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View Online at https://aerobasegroup.com/nsn/5962-01-067-8314

Body Length:

Between 0.755 inches and 0.790 inches

Body Width:

Between 0.265 inches and 0.300 inches

Body Height:

Between 0.155 inches and 0.175 inches

Maximum Power Dissipation Rating:

625.0 milliwatts

Operating Tempurature Range:

+0.0/+75.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Radar set type an/fps-115

Features Provided:

Hermetically sealed and monolithic and positive outputs and w/storage and programmable and programmed and w/open collector and

bipolar and w/enable and w/decoded output

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

10 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

5.5 volts power source

Time Rating Per Chacteristic:

35.00 nanoseconds propagation delay time, low to high level output and 35.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Test Data Document:

04761-640-200046 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

